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Abstract. One of important issues of molecular spintronics is the control and manipulation of charge transport and, in particular, its spin polarization through single-molecule junctions. Using *ab initio* calculations, we explore spin-polarized electron transport across single benzene derivatives attached with six different anchoring groups (S, CH₃S, COOH, CNH₂NH, NC and NO₂) to Ni(111) electrodes. We find that molecule-electrode coupling, conductance and spin polarization (SP) of electric current can be modified significantly by anchoring groups. In particular, a high spin polarization (SP > 80%) and a giant magnetoresistance (MR > 140%) can be achieved for NO_2 terminations and, more interestingly, SP can be further enhanced (up to 90%) by a small voltage. The S and CH_3S systems, on the contrary, exhibit rather low SP while intermediate values are found for COOH and CNH₂NH groups. The results are analyzed in detail and explained by orbital symmetry arguments, hybridization and spatial localization of frontier molecular orbitals. We hope that our comparative and systematic studies will provide a valuable quantitative information for future experimental measurements on that kind of systems and will be useful for designing high-performance spintronics devices.

Keywords: Molecular spintronics, NEGF-DFT calculations, Spin filtering, Single molecule junctions

19 1. Introduction

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Molecular (organic) spintronics [1] is a rapidly developing field of research, aiming at the manipulation of both electron charge and spin in molecular-based devices, taking advantage of large spin relaxation length across purely organic molecules due to small spin-orbit interactions. The one of most fundamental and crucial properties here is the

spin polarization (SP) of the current by ferromagnet/organic interface [2, 3, 4], which 24 can be defined as SP = $(G_{\downarrow} - G_{\uparrow})/(G_{\uparrow} + G_{\downarrow}) \times 100\%$, where G_{\uparrow} and G_{\downarrow} are spin up 25 (majority) and spin down (minority) conductance, respectively. Recently, it has been 26 shown that the SP in single molecule junctions can be tunned by a mechanical strain [5], 27 an orbital symmetry considerations [6], and spin-dependent quantum interference effect 28 [7] etc. Understanding physical and chemical mechanisms involved in spin injection at 29 the hybrid interfaces for further design of possible molecular-based devices with large 30 SP and high conductance is one of the most important issues in this field. 31

The anchoring groups (also known as "linkers") placed at extremities of the 32 molecule are responsible for establishing a stable mechanical contact and efficient 33 molecule/metal electronic coupling. For this reason, thiol (-SH) [8] and thiolate (-S)34 [9, 10] have become the most widely used anchoring groups due to strong covalent 35 gold-sulfur bonding. However, it was argued extensively that the conductance of thiol 36 based molecular junctions depends strongly on the binding geometry [11]. Therefore, 37 many theoretical and experimental efforts were made to explore various anchoring groups 38 such as methythiol $(-CH_3S)$ [12, 13], carboxyl-acids (-COOH) [8, 14], amidine $(-NH_2)$ 39 [10, 15], isonitrile (-NC) [16, 17], nitrile (-N) [18], nitro (-NO₂) [19, 20], etc. These 40 investigations ended up with two general conclusions : first, the chemical nature of 41 anchoring groups strongly affects the energy level alignment of molecular frontier orbitals 42 with respect to the metal Fermi level; second, the degree of hybridization between 43 molecule and metal changes dramatically with anchoring groups. 44

For 3d ferromagnetic materials, the s band is almost non spin-polarized while the 3d45 bands are spin-split due to the exchange interactions. As a result, the density of states 46 (DOS) of 3d ferromagnetic materials (such as Fe, Co, or Ni) show a spin polarization of 47 about $30 \sim 40\%$ at the Fermi energy. Therefore, when organic molecules are contacted 48 with 3d metals, a selective hybridization occurs at the molecule-metal interface for 49 spin up and down channels. For example, due to large $\pi - d$ hybridization at the 50 ferromagnetic metal/organic interfaces, high spin polarization [2, 21], controllable ferro-51 or antiferromagnetic interlayer exchange coupling [22], giant magnetoresistance [23] and 52 enhanced perpendicular magnetic anisotropy [24] were reported (a detailed discussion 53 on molecular spinterface can be found in Ref. [25]). 54

Previous studies were mainly focused on the effect of anchoring groups on 55 charge transport properties with nonmagnetic electrodes (Au, Ag and Cu etc). The 56 investigation of spin polarization via various anchoring groups at organic spinterface was 57 pointed out recently [26, 27]. In this work, based on spin-polarized *ab initio* transport 58 calculations, we present a comparative and systematic study of the impact of anchoring 59 groups on spin-dependent transport with ferromagnetic electrodes. More specifically, we 60 have chosen a benzene as a core structure and have studied the spin-dependent transport 61 for a series of $Ni(111)/X - (C_6H_4) - Y/Ni(111)$ junctions, where terminations X,Y could 62 be S, CH₃S, COOH, CNH₂NH, NC or NO₂ groups, as demonstrated in Fig. 1. These 63 systems are chosen because Ni-based spin valves were firstly proposed by Emberly et al 64 [28] as a prototypical molecular spintronic system, and later on were studied extensively 65

by several theory groups based on *ab initio* methods [29, 30] and also successfully created 66 by mechanically controlled break junction (MCBJ) experiment [31]. Importantly, as will 67 be discussed later, all these molecules have frontier orbitals which, by symmetry, do not 68 overlap with the Ni electrode's s states. Due to symmetry arguments proposed by us 69 recently [6, 32], all the junctions are therefore expected to display rather high SP of 70 conductance which is indeed confirmed by our calculations. We find, moreover, that 71 among all considered molecules the one with NO_2 terminations, M6 in Fig. 1, presents 72 very high values of SP and of total conductance at the same time. In addition, high spin 73 filtering in M6 $(-NO_2)$ is accompanied by huge magnetoresistance (MR) ratio (about 74 140%) which measures the change in resistance (or conductance) between parallel and 75 antiparallel magnetic configurations of two ferromagnetic electrodes. These findings 76 make therefore M6 molecule the most promising candidate for possible spintronics 77 applications. 78

The paper is organized as follows. In Sec. 2, we present computational methods and models used in this work. In Sec. 3, the electronic structure and transport properties of benzene derivative molecules with different anchoring groups in equilibrium will be presented. Then, we will present the non-equilibrium transport phenomena with a particular focus on their SP and MR. Finally, the conclusion will be drawn in Sec. 4.

⁸⁴ 2. Calculation methods and models

The geometry optimization of molecular junctions was carried out using plane waves 85 QUANTUM-ESPRESSO (QE) package [33] within the density functional theory (DFT). 86 We used PBE [34] exchange-correlation functionals and ultrasoft pseudopotentials (PP) 87 to describe electron-ion interactions. Plane-wave energy cutoffs of 30 and 300 Ry were 88 used for wave functions and charge density, respectively. Molecular junctions were 89 described in a supercell containing a molecule and two 4-atom Ni pyramids attached 90 to both sides to Ni(111) slabs with 4×4 periodicity in the XY plane (16 atoms per 91 layer) containing 6 layers on each side as shown in Fig. 1. During ionic relaxation, three 92 bottom layers on both sides were kept fixed at their bulk positions while a molecule and 93 other Ni layers were allowed to relax until atomic forces were less than 10^{-3} Rv/Bohr. 94 Relaxation was performed using $(2 \times 2 \times 1)$ k-point mesh. 95

After the atomic relaxation, *ab initio* spin-polarized electronic transport properties 96 for different molecular junctions were evaluated using the TRANSIESTA code [35] which 97 employs a non-equilibrium Green's function (NEGF) formalism combined with DFT. 98 We used Troullier-Martins norm-conserving pseudopotentials [36], PBE functional and 99 an energy cutoff for the real-space mesh of 250 Ry. Valence electron wavefunctions were 100 expanded in a basis of local orbitals in SIESTA [37]. A double ζ plus polarization (DZP) 101 basis set with an energy shift of 50 meV was used, which resulted, as we have checked, in 102 a good agreement with QE results for both magnetic properties and energy alignments 103 (see Fig. 6 in Appendix A). The convergence tolerance for self-consistent loop was set 104 to 10^{-4} eV and the Brillouin zone was sampled by $6 \times 6 \times 1$ k-point mesh. 105



Figure 1. Schematic representation of optimized atomic structures for benzenebased molecules with different anchoring groups connecting two Ni(111) electrodes. The investigated six molecules in this work are: (a) 1,4-benzenedithiolate (M1), (b) benzene, 1,4-bis (methylthio) (M2), (c) 4-(methylthio) benzonic acid (M3), (d) benzene, 1,4-amine and methylthio (M4), (e) 1,4-phenylene diisocyanide (M5) and (f) 1,4-dinitrobenzene (M6). Note that M3 and M4 are asymmetric molecular junctions with different anchoring groups on the left and right sides. Z is the charge transport direction which is parallel to the junction axis.

	d (Å)	$d_{\text{Ni-X}}$ (Å)	$d_{\text{Ni-Y}}$ (Å)	$M_s (\mu_{\rm B})$	$G_{\uparrow} \ (G_0 = e^2/h)$	$G_{\downarrow} \ (G_0 = e^2/h)$	$G_{\rm tot} \ (G_0 = e^2/h)$	SP (%)
M1	13.78	2.14	2.14	0.28	1.48×10^{-1}	7.15×10^{-2}	2.20×10^{-1}	-34.99
M2	13.45	2.16	2.16	-0.02	9.81×10^{-3}	7.77×10^{-3}	1.76×10^{-2}	-11.50
M3	14.03	2.11	1.89	-0.07	1.73×10^{-2}	8.80×10^{-2}	9.77×10^{-2}	64.49
M4	14.24	2.12	1.89	-0.04	1.51×10^{-2}	4.10×10^{-2}	5.62×10^{-2}	46.00
M5	15.25	1.78	1.78	-0.14	1.67×10^{-2}	2.78×10^{-1}	2.50×10^{-1}	87.46
M6	14.24	2.04	2.04	0.31	3.54×10^{-2}	3.21×10^{-1}	3.56×10^{-1}	80.13

Table 1. Optimized junction distances, induced molecular spin moment (M_s) (calculated from spin-polarized molecular DOS integrated up to the Fermi energy as shown in Fig. 7), spin-resolved and total conductances (in the unit of $G_0 = e^2/h$ which is conductance quantum per spin) in parallel spin configuration and its spin polarization.

Spin-resolved (denoted by spin index $\sigma = \uparrow, \downarrow$) transmission function, depending on energy *E* and applied bias $V_{\rm b}$, is given by:

$$T_{\sigma} = \operatorname{Tr}[\Gamma_{L,\sigma}G_{\sigma}^{r}\Gamma_{R,\sigma}G_{\sigma}^{a}], \qquad (1)$$

where all matrices depend also on E and $V_{\rm b}$ and have dimension of the scattering region (or extended molecule) including the molecule itself and some parts of left and right electrodes (where screening takes place). $G_{\sigma}^{r/a}$ are the retarded/advanced Green's functions:

$$G_{\sigma}^{r/a} = \left[(E \pm i\eta) S - H_{\sigma}^{C} - \Sigma_{L,\sigma}^{r/a} - \Sigma_{R,\sigma}^{r/a} \right]^{-1}$$
(2)

with η is an infinitesimal positive number, S is the overlap matrix, H_{σ}^{C} is the Hamiltonian matrix for the scattering region and $\Sigma_{L/R,\sigma}^{r/a}$ are retarded or advanced self-energies due to left/right electrodes. Coupling matrices $\Gamma_{L/R,\sigma}$ are evaluated from corresponding self-energies as $\Gamma_{L/R,\sigma} = i(\Sigma_{L/R,\sigma}^{r} - \Sigma_{L/R,\sigma}^{a})$.

Finally, the spin-dependent charge current is obtained from the Landauer-Büttiker formula:

$$I_{\sigma}(V_{\rm b}) = \frac{e}{h} \int_{-\infty}^{+\infty} dE [f(E,\mu_L) - f(E,\mu_R)] T_{\sigma}(E,V_{\rm b}), \qquad (3)$$

where $f(E, \mu_{L/R})$ are Fermi-Dirac distribution functions, and $\mu_{L/R}$ are electrochemical potential of left/right electrodes.

120 3. Results and discussion

The optimized geometries of molecular junctions are shown in Fig. 1. We first performed 121 atomic relaxations of a Ni/molecule interface to obtain an electrode-molecule separation 122 and geometry, and then carried out full relaxations by attaching the second electrode 123 at the previously calculated molecule-metal distance. Let us stress that relaxations 124 have been performed starting from several possible initial configurations in order to find 125 the minimum energy configuration. For example, the nitro $(-NO_2)$ -terminated molecule 126 prefers to bind through double Ni–O bonds on each side rather than with Ni–N or single 127 Ni–O bonds as seen in Fig. 1 (f). Some important structural parameters, electronic and 128 transport properties are summarized in Table 1. Note that M3 and M4 are asymmetric 129 junctions with two different linking groups on left and right sides while all the others 130 are symmetric. Small induced (by Ni electrodes) spin moments on M1 and M6 were 131 found to be positive ("ferromagnetic" molecule/Ni coupling) while for other molecules 132 - negative ("antiferromagnetic" coupling). Spin-dependent conductance, G_{σ} , is given 133 by the Landauer-Büttiker formula, $G_{\sigma} = G_0 T_{\sigma}(E_F)$, where $G_0 = e^2/h$ is the quantum 134 conductance per spin (e being the electron charge and h Plank's constant) and $T_{\sigma}(E_F)$ 135 is the transmission function for spin $\sigma = \uparrow, \downarrow$ at the Fermi energy. The calculated total 136 conductance (summed over spin up and down channels) of M1 at zero bias voltage 137 was found to be about $0.22G_0$ which is in agreement with previous calculations [38]. 138 Additionally, the SP of M1 and M2 was found to be negative $(G_{\uparrow} > G_{\downarrow})$ while all 139 the junctions have positive SP. Previous DFT calculations showed also a negative SP 140 in Ni/BDT/Ni junction [29]. Moreover, M5 and M6 exhibit large spin polarization of 141 about 87% and 80% and high conductance of about $0.25G_0$ and $0.35G_0$, respectively, so 142 they appear to be most attractive for possible future applications in spintronics devices. 143 First, we plot in Fig. 2 highest occupied molecular orbitals (HOMO) as well as 144 lowest unoccupied molecular orbitals (LUMO) for all the molecules in gas phase. We 145 found that all the orbitals are of π -type (odd with respect to the molecular YZ plane) 146



Figure 2. HOMO and LUMO molecular orbitals in gas phase for the same molecules as in Fig.1. Isosurfaces of positive and negative isovalues are shown in red and blue, respectively. Note that all the orbitals are of π -type (odd with respect to the YZ plane) except of HOMO and HOMO-1 for M6 (which are even). The latter orbitals are nearly degenerate (split by about 0.1 eV) and represent bonding/anti-bonding combinations of end-group originated states.

except of HOMO and HOMO-1 for M6 case which are split by only about 0.1 eV and 147 are of σ -type (even with respect to the YZ plane). Interestingly, these M6 orbitals 148 are both localized on $-NO_2$ anchoring groups forming a kind of bonding/anti-bonding 149 states, even or odd with respect to the transport direction Z. Since the molecules have 150 relatively small tilting angles in the YZ plane, all frontier π -orbitals have rather small 151 overlap with spin up s-states of Ni apex atoms (two Ni atoms which contact the molecule 152 as indicated in Fig. 1a) while a strong coupling with spin down d_{xz} states is expected. 153 That should lead to rather strong SP of conductance due to orbital symmetry argument 154 [6, 32]. This reasoning is also valid for HOMO and HOMO-1 orbitals of M6, though 155 they are not of π -type. They are still orthogonal to Ni apex s-states because of odd 156 symmetry with respect to the XZ plane and will only transmit spin down electrons 157 injected by Ni apex d_{uz} orbitals. 158

To better understand conductance as well its SP discussed above, we show in Fig. 159 3 spin-resolved transmission functions at zero bias in the parallel spin configuration of 160 Ni electrodes. The black and red curves show the spin up and down transmissions, 161 respectively. First, we note that energy alignment of frontier molecular orbitals with 162 respect to the Fermi energy, imposed by Ni electrodes, changes drastically with the 163 anchoring groups. While for M1 and M6 we find that the transport is dominated by the 164 HOMO (p-type current by holes), in the case of M2, M3, M4 and M5, the conduction 165 takes place through the LUMO (n-type current by electrons). Second, the width of 166 transmission features is attributed to the degree of molecule level hybridization with 167 electrode states. Therefore, much more structured T(E) with broader features is found 168 for spin down due to extra d_{\downarrow} states of Ni in the vicinity of the E_F . As a general 169 feature, two peaks are often seen in spin down transmission: the first one at about -0.5170



Figure 3. Spin-resolved zero-bias transmission functions (in logarithmic scale) with the parallel magnetic alignment of two Ni electrodes for (a) M1, (b) M2, (c) M3, (d) M4, (e) M5 and (f) M6 molecular junctions. Spin up and down channels are plotted by black and red lines, respectively. Note that the zero of energy is at the Fermi level. Positions of HOMO and LUMO for spin up is marked by black arrow.

¹⁷¹ eV (see, e.g., Fig. 3b-e) and another one at about 0.4 eV (see, e.g., Fig. 3a,c,d,f) which ¹⁷² originate from $d^{\downarrow}_{x^2-y^2,xy}$ and $d^{\downarrow}_{zx,zy}$ states, respectively, of Ni apex atoms. Here, we mark ¹⁷³ the position of HOMO and LUMO for spin up by black arrow. For the spin down, the ¹⁷⁴ position of HOMO and LUMO are much more delocalized due to strong hybridization ¹⁷⁵ between π orbital and $(s^{\downarrow} + d^{\downarrow})$ states of Ni apexes. For more details, please see the ¹⁷⁶ projected DOS on molecules as shown in Fig. 7 (see Appendix B).

We first discuss the electron-donating anchoring groups such as M1 and M6. For 177 M1, rather sharp spin up peak at about -0.2 eV originates from the HOMO weakly 178 hybridizing with s_{\uparrow} states of Ni apexes and with other orbitals of deeper Ni atoms. 179 For the spin down, much broader feature in transmission is observed at energies -1.2180 eV < E < 1 eV coming from the coupling of HOMO with $(s^{\downarrow} + d^{\downarrow})$ states of Ni apexes. 181 In particular, the peak at about 0.5 eV is related to the offset of Ni d_{xz}^{\downarrow} states appearing 182 at about E < 1 eV. Another peak in both spin channels at about 3.2 eV is attributed to 183 the LUMO level. This result is in good agreement with previous *ab initio* calculations 184 [38, 29]. Interestingly, in the case of M6, compare to M1, the HOMO-derived spin up 185 transmission peak is more sharp, resulting in significantly reduced spin up conductance 186 and thus higher spin polarization. This can be explained by two reasons as follows. 187 The first one is the orbital symmetry argument as mentioned before. During atomic 188 relaxations, the planar configuration of M1 in the YZ plane is not perfectly conserved, so 189 it slightly tilts in the X direction and moves out of the YZ plane. This distortion turns 190

out to be much smaller for more symmetric M6 with double Ni-O bonds on both sides. 191 As a result, the HOMO of M1 is expected to overlap more with Ni apex s-states which 192 leads to broader spin up transmission peak compared to M6 case. A similar result was 193 also reported previously in nonmagnetic molecular junctions which can switch between 194 high and low conductance states by a mechanical strain [39]. The second reason is the 195 rather strong localization of HOMO and HOMO-1 of M6 on the linking groups (the 196 orbitals are decoupled in the middle) compared to rather delocalized HOMO of M1 (see 197 Fig. 2a,f). By means of stability of molecular junctions with NO_2 -termination, we 198 note that two contradictory results have been reported. L. A. Zotti et al [40] concluded 199 that NO_2 -terminated tolanes form rather stable molecular junctions under ambient 200 conditions with MCBJ while V. Kaliginedi *et al* [41] showed the molecular junctions 201 formed with NO_2 -caped molecule are rather unstable. The authors argued that this 202 difference may arise from the nature of different experimental conditions in both studies. 203 Moreover, R. Vardimon et al [42] successfully created nickel oxide atomic junctions due 204 to strong chemisorption at the Ni–O contacts. Therefore, we hope that the M6 $(-NO_2)$ 205 junction is rather stable with Ni electrodes, and of course this needs to be confirmed by 206 future experiments. 207

We now turn our attention to the electron-accepting groups, *i.e.*, M2, M3, M4 208 Here, the transport is dominated by LUMO. For M2, when a thiolate and M5. 209 (-S) was replaced by a methylthiol $(-CH_3S)$, the molecule-metal coupling strength 210 is significantly reduced, resulting in a narrower LUMO resonance peak at about 1.5 211 eV. Moreover, due to LUMO symmetry (Fig. 2b) it does not overlap with Ni apex 212 $d_{xz,yz}^{\downarrow}$ states which explains that no increase of spin down transmission is observed 213 at around 0.4 eV where those d-states dominate the Ni down DOS. That explains 214 rather low spin down conductance and SP for M2 compared to M1 case. Our results 215 have a general agreement with very recent experimental measurements on thiolate and 216 methylthiol terminated systems [43, 44] with Au electrodes. Moreover, in Ref. [44], 217 the authors confirmed experimentally that S-Au and CH₃S-Au are chemisorption and 218 physisorption mechanisms, respectively. Next, if we replace one of $-CH_3$ by -COOH219 and $-CNH_2NH$, forming M3 and M4 asymmetric junctions, the LUMO approaches to 220 E_F , leading to enhanced conductance. For these molecules, the LUMO (Fig. 2c,d) will 221 overlap now with $d_{xz,yz}^{\downarrow}$ Ni states so that larger spin down conductance (and noticeable 222 SP) is again recovered for M3 and M4 junctions which show in fact rather similar 223 transmission features. In the case of M3 junction, experimentally, it has been shown 224 that the formations of $-COO^{-}$ and -COOH in solution depend on the pH condition 225 [8, 14]. Additionally, D. Sheng et al used -COOH in their ab initio calculations [45] 226 for alkane molecular wires. The result presented in Fig. 3c, we used COOH–Ni contact 227 for M3 junction, as shown in Fig. 1c. In addition, we also investigated the M3 junction 228 with one removed "H" atom forming COO⁻-Ni bond at the interface (see Appendix D). 229 Interestingly, as shown in Fig. 8, when the "H" atom is removed, the charge transport 230 is dominated by HOMO rather than LUMO due to loss of one electron. Moreover, 231 the conductance values for both spins are bout one order of magnitude smaller than 232

corresponding M3 junction because of super sharp HOMO and its localized features 233 around "O" atoms at the interface (see inset in Fig. 8b). Finally, for M5 molecule 234 rather broad LUMO-derived transmission feature is seen about 0.75 eV, significantly 235 increasing for spin down channel upon approaching the Fermi level due to noticeable 236 coupling to Ni spin down d-states. We note that the DFT transport scheme tends to 237 overestimate the conductance of molecular junctions relative to experiments due to the 238 underestimation of their gap between occupied and unoccupied states. Quasiparticle 239 GW self-energy has been recognized as a good approximation to describe accurately the 240 energy level alignment at the molecule-metal interface. However, it has been shown that 241 GW corrections affect rather unoccupied orbitals (poorly described within the ground 242 state DFT) while occupied levels (in particularly, the HOMO) are only slightly altered 243 [46, 47]. Since the charge transport in M1 and M6 is dominated by HOMO level, we 244 hope that the mean-field DFT results are enough to provide reliable comparative results. 245 On the other hand, for LUMO dominant junctions such as M2, M3, M4 and M5, smaller 246 conductance values are expected (for both spin channels) with more sophisticated GW247 self-energy. Moreover, the DFT error is in general systematic, thus conductance ratios 248 are usually in good agreement with experiment, for instance the rectification ratios 249 predicted by NEGF-DFT were found to be reliable [48, 49]. So we believe that the spin 250 filtering ratios presented in this work are reliable as well. In summary, we believe that 251 the DFT-error introduced here plays a role in a quantitative basis but should not affect 252 our main conclusions. 253

Having understood the transport properties at equilibrium, we now turn to out-of-254 equilibrium situation with a small bias voltage $(V_{\rm b})$, up to 0.6 V. At each voltage, the spin 255 up and down currents are determined self-consistently under non-equilibrium condition 256 using the Landauer-Büttiker formula (see Eq. 3). The results show various trends for 257 different anchoring groups. Clearly, spin down current (plotted with negative values) is 258 significantly larger than the corresponding spin up one (plotted with positive values) as 259 shown in Fig. 4a. More importantly, for M6, the spin up current increases very slowly 260 with an approximately linear trend. On the contrary, the spin down current increases 261 much more rapidly which results in a high spin injection efficiency. The pronounced 262 increase of spin down currents for M1 and M6 indicates a strong metal/molecule orbital 263 coupling close to E_F . On the contrary, for M3 and M5, the current for both spin 264 channels increase much slower. For spin up channel, small currents are attributed to 265 the fact that the LUMO resonance lie at about 0.5 and 0.7 eV (see Fig. 3) for M3 and 266 M5, respectively, which are not included in the explored bias window. In addition, we 267 find that M2 and M4 has lowest currents for both spin channels. 268

The spin polarization of the current at a bias voltage is evaluated as, SP = $(I_{\downarrow} - I_{\uparrow})/(I_{\uparrow} + I_{\downarrow}) \times 100\%$, where I_{\uparrow} and I_{\downarrow} are spin up and down currents, respectively. Note that at equilibrium, the SP was evaluated from conductance values. For zero bias voltage, the SP for M5 and M6 are more than 80%. Interestingly, when the bias voltage is applied, the SP of M6 is further enhanced up to more than 90%. On the contrary, the SP of M5 is slightly decreased. Moreover, for M3, the SP is less than 65% under



Figure 4. (a) Current-voltage characteristics for spin up (positive values) and spin down (negative values) channel for M1, M2, M3, M4, M5 and M6 molecular junctions, (b) Corresponding SP as a function of voltage. Note that conductance values are used to evaluate SP in equilibrium case.

²⁷⁵ zero bias, but it can become as large as 80% at $V_b = 0.6$ V. On the other hand, the SP ²⁷⁶ of M4 slightly increases when the bias voltage is applied. Interestingly, the SP of M1 ²⁷⁷ and M2 changes sign when the bias voltage is applied but remains relatively low.

Since the M6 exhibits large SP as well as high conductance, we have also studied its 278 magnetoresistance (MR) property which measures the change in total current between 279 the parallel (P) and antiparallel (AP) magnetic alignments of Ni electrodes. In the 280 linear regime it can can be calculated as MR = $(G_{\rm P} - G_{\rm AP})/G_{\rm AP} \times 100\%$, where $G_{\rm P}$ 281 and G_{AP} are total conductances (sum of spin up and down contributions) at zero bias 282 for P and AP magnetic configurations, respectively. We present in Fig. 5 the total 283 transmissions for two magnetic cases. As expected, in addition to the large SP the M6 284 junction also shows very high MR, as large as 140%. It is much larger than the MR 285 found for M1 junctions, of about 27%, as reported in Ref. [29], confirming once again 286 very good spin filtering properties of symmetric NO₂ anchoring groups. In appendix D, 287 we summarized the transmission functions of anti-parallel spin configurations (Fig. 9) 288



Figure 5. Total transmission functions (in logarithmic scale) of M6 junction at zero-bias voltage for both parallel and anti-parallel magnetic configurations of two Ni electrodes. Note that spin up and down contributions (equal due to symmetry in the antiparallel case) are summed in both configurations. The calculated MR was found to be as large as 140%.

and corresponding MR (Table 2) values for all six molecular junctions.

290 4. Conclusions

To conclude, by using a combination of density functional theory (DFT) and non-291 equilibrium Green's function (NEGF) formalism, we have investigated the effect of 292 anchoring groups on spin-polarized transport through benzene-derivative molecular 293 junctions joining two ferromagnetic Ni(111) electrodes. It was found that anchoring 294 groups have a strong impact on the energy alignment of relevant molecular orbitals with 295 respect to the Fermi level and the degree of molecule-metal hybridization. Therefore, 296 the choice of anchoring groups indeed strongly affects the conductance of the molecular 297 junction and its spin polarization, SP. According to our study, M6 $(-NO_2)$ junctions 298 exhibit overall the best performance with high conductance (and also the current), 299 large SP (>80%) as well as giant MR of about 140%. Interestingly, the SP can 300 be further enhanced (up to 90%) by a small voltage. It was attributed to a rather 301 sharp/broad HOMO-derived resonance in spin up/down transmission around the Fermi 302 energy dictated by the HOMO symmetry and its spatial distribution. The S and CH₃S 303 systems, on the contrary, exhibit rather low SP while intermediate values are found 304 for COOH and CNH₂NH groups. It has been found, in addition, that the large SP 305 of M5 (-NC) is slightly decreased with the voltage. We believe that our comparative 306 and systematic studies will enrich the understanding of the role of anchoring groups on 307 spin-polarized transport of molecular junctions and will be useful for further studies and 308 applications in molecular spintronics. 309

310

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³¹⁵ Appendix A: Comparison between SIESTA and QE results



Figure 6. (a) Spin-resolved total density of states (DOS) of bulk fcc-Ni for spin up (black) and down (red), calculated by SIESTA (top) with NCPP and by QE with ultrasoft PP (down). The exchange splitting from SIESTA is about 0.16 eV larger, which results in a 0.05 $\mu_{\rm B}$ larger magnetic spin moment compare to QE results. (b) Spin-dependent projected DOS on molecule for M6 junction calculated by SIESTA and QE. A very good overall agreement is found between SIESTA and QE results.

For fcc-Ni as seen in Fig. 6 (a), the magnetic moments calculated by QE was found to be about 0.65 $\mu_{\rm B}$ while the SIESTA within DZP basis gives about 0.70 $\mu_{\rm B}$. The small discrepancy between QE and SIESTA on spin moment can be traced to the use of NCPPs in SIESTA, versus ultrasoft PPs in QE. The similar results were also reported in Ref.[23, 50]. In addition, the single ζ (SZ) and SZP basis sets of SIESTA give the spin moment of 0.78 $\mu_{\rm B}$ and 0.74 $\mu_{\rm B}$, respectively, suggesting that the DZP basis set for Ni is the best one in terms of more accurate description of spin moment.

In order to check the reliability of our DZP basis sets used in this work, we also compared the spin-dependent projected DOS on molecule for M6 junctions as plotted in Fig. 6b. A good agreement between QE and SIESTA results is found in terms of energy level alignments, indicating the validity of our DZP basis set.

Appendix B: Projected DOS on molecules with the parallel spin configuration

To identify the positions of molecular levels, we display in Fig. 7 the projected DOS on molecule with the parallel magnetic alignment of two Ni electrodes for six molecular junctions. HOMO and LUMO peaks are clearly seen.

Interestingly, we found that LUMO+1 of M6 (see inset of Fig. 7f) is strongly localized on 4 carbon atoms of the molecule and is completely decoupled from electrodes, which explains that no LUMO+1 derived peak was observed in the transmission curve plotted in Fig. 3 (f).



Figure 7. Spin-resolved projected DOS on molecule with the parallel magnetic alignment of two Ni electrodes for (a) M1, (b) M2, (c) M3, (d) M4, (e) M5 and (f) M6 molecular junctions. Spin up and down channels are plotted by black and red lines, respectively. The local DOS in the energy window of LUMO+1 for M6 is also plotted in the inset. Note that the zero of energy is at the Fermi level.

336 Appendix C: M3 junction with removed single "H"

When the "H" atom is removed, the electron transport is dominated by HOMO rather than LUMO due to loss of one electron (see Fig. 8). Interestingly, the conductance values for both spins are bout one order of magnitude smaller than corresponding M3 junction because of super sharp HOMO and its localized features around "O" atoms at the interface (see inset in Fig. 8b).



Figure 8. M3 molecular junction with COO⁻-Ni contact, here one "H" atom is removed. Spin-resolved transmission function (a) and projected DOS on molecule (b). Spin up and down channels are plotted by black and red lines, respectively. Note that the zero of energy is at the Fermi level. Local DOS at the energy range of HOMO peak for spin up is plotted in the inset.

³⁴² Appendix D: Spin-dependent T(E) with the anti-parallel spin configuration

We present in Fig. 9 the spin-dependent transmission functions for the anti-parallel magnetic configuration of two Ni electrodes. Due to symmetry, spin up and spin down T(E) superpose for symmetric junctions (M1, M2, M5 and M6) while they are slightly different for asymmetric cases (M3 and M4). The corresponding magnetoresistance values are summarized in Table. 2.

	M1	M2	M3	M4	M5	M6
MR $(\%)$	35	10	30	38	92	142

Table 2. Calculated magnetoresistance, MR = $(G_{\rm P} - G_{\rm AP})/G_{\rm AP} \times 100\%$, of six molecular junctions.

348 References

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Tuning spin filtering by anchoring groups in benzene derivative molecular junctions 15

Figure 9. Spin-resolved zero-bias transmission functions (in logarithmic scale) with the anti-parallel magnetic alignment of two Ni electrodes for (a) M1, (b) M2, (c) M3, (d) M4, (e) M5 and (f) M6 molecular junctions. Spin up and down channels are plotted by black and red lines, respectively. Note that the zero of energy is at the Fermi level.

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